















## Bill of Materials

## <Parameter Title not found>

Source Data From: RX\_Banda\_Aerea.PrjPCB

Project: RX\_Banda\_Aerea.PrjPCB

Variant: None

Creation Date: 31/03/2010 3:23:35

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Footprint	Comment	LibRef	Designator	Description	Quantity
C0805	Cap Pol3	Cap Pol3	C1, C3, C4, C5, C6, C7, C8, C9, C10, C1 C13, C14, C15, C17, C18, C19, C20, C2 C22, C23, C24, C25, C26, C27, C28, C2	. ,	53
			C31, C32, C33, C34, C35, C36, C37, C3		
			C39, C40, C41, C42, C43, C44, C45, C4		
			C47, C48, C50, C51, C53, C55, C57, C5		
			C59, C60, Cp1		
В	Cap Pol1	Cap Pol1	C2, C16, C30, C49, C52, C54	l Polarized Capacitor (Radial)	6
C1206	Cap Semi	Cap Semi	C12, C56	Capacitor (Semiconductor SIM Model)	2
SOT323_N	BAS70-04W	BAS70-04W	D1, D2	Schottky Barrier Double Diode	2
Ind_5mm	Ind2	Ind2	Ind1		1
Ind_4mm	Ind2	Ind2	Ind2		1
NTH12_2	Ind2	Ind2	Ind3		1
3261	Inductor	Inductor	L1, L2, L3, L4	Inductor	4
AXIAL-0.3	Res1	Res1	L5	Resistor	1
HDR1X3	Header 3	Header 3	P1, P4	Header, 3-Pin	2 3 2 5
HDR1X2	Header 2	Header 2	P2, P3, P6	Header, 2-Pin	3
SOT23_N	BFS17	BFS17	Q1, Q2	NPN 1 GHz Wideband Transistor	2
SOT23_N	PMBF4391	PMBF4391	Q3, Q4, Q5, Q6, Q7	N-channel Silicon Junction Field-effect Transistor	5
2012[0805]	Res Semi	Res Semi	R2, R3, R4, R5, R6, R7, R8, R9, R10, R1 R12, R13, R14, R15, R16, R17, R18, R1		34
			R20, R22, R23, R24, R25, R26, R27, R2		
			R29, R30, R31, R32, R33, R34, R?		
Potenciometr o	Pot	Pot	R21		1
NTH12_4	Toroide	Transformador_ Toroide	T1, T2, T3		3
SA602	SA602	SA602A	U1, U3		2
UPC2710TB2	uPC2710TB	uPC2710TB	U2		1
N08E	LM386N-1	LM386N-1	U4	Low Voltage Audio Power Amplifier	1
626-05	TL081CP	TL081CP	U5	JFET-Input Operational Amplifier	1
Z03A	LM78L05ACZ	LM78L05ACZ	U6	3-Terminal Positive Regulators	1
HC-49US	ECS-35-17-4-3I	ECS-35-17-4-3I	Y1	Crystal Oscillator, 3rd In-Line Lead Version	n 1
HC-49U	ECS-10-13-1	ECS-10-13-1	Y2	Crystal Oscillator	1
HC-49U	ECS-49-20-1	ECS-49-20-1	Y3, Y4, Y5, Y6	Crystal Oscillator	4
Approved		Notes			133
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